RoHS
Available on commercial versions

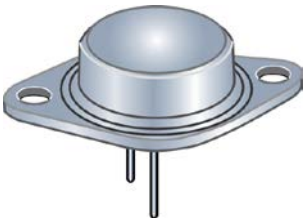
NPN Darlington Power Silicon Transistor

Qualified per MIL-PRF-19500/523

Qualified Levels:
JAN, JANTX, and JANTXV

DESCRIPTION

This high speed NPN transistor is rated at 10 amps and is military qualified up to the JANTXV level. This TO-204AA isolated package features a 180 degree lead orientation.



TO-204AA (TO-3) Package

Important: For the latest information, visit our website http://www.microsemi.com.

FEATURES

- JEDEC registered 2N6383 through 2N6385
- JAN, JANTX, and JANTXV qualifications are available per MIL-PRF-19500/523. (See part nomenclature for all available options.)
- RoHS compliant versions are available (commercial grade only)

APPLICATIONS / BENEFITS

- Military and other high reliability applications
- High frequency response
- TO-204AA case with isolated terminals

MAXIMUM RATINGS @ T_A = +25 °C unless otherwise noted

Parameters/Test Conditions		Symbol	Value	Unit
Junction and Storage Temperature		T_J and T_{STG}	-55 to +175	°C
Thermal Resistance Junction-to-Case		$R_{\Theta JC}$	1.75	°C/W
Collector-Emitter Voltage	2N6383	V_{CEO}	40	V
	2N6384		60	
	2N6385		80	
Collector-Base Voltage	2N6383	V_{CBO}	40	V
	2N6384		60	
	2N6385		80	
Emitter-Base Voltage		V_{EBO}	5	V
Total Power Dissipation	@ T_A = +25 °C (1)	P_T	6.0	W
	@ T_C = +25 °C (2)		100	
Base Current		I_B	0.25	A
Collector Current		I_C	10	A

Notes: 1. Derate linearly 34.2 mW/°C above T_A > +25 °C.
2. Derate linearly 571 mW/°C above T_C > +25 °C.

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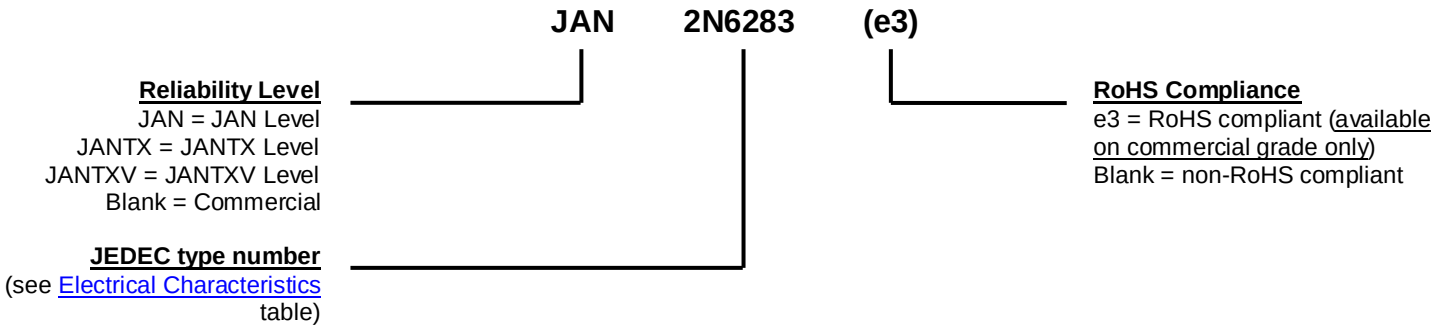
MECHANICAL and PACKAGING

- CASE: Industry standard TO-204AA (TO-3), hermetically sealed, 0.040 inch diameter pins
- FINISH: Solder dipped tin-lead over nickel plated alloy 52 or RoHS compliant matte-tin plating. Solderable per MIL-STD-750 method 2026.
- POLARITY: NPN (see schematic)
- MOUNTING HARDWARE: Consult factory for optional insulator and sheet metal screws
- WEIGHT: Approximately 15 grams
- See package dimensions on last page.

PART NOMENCLATURE



SYMBOLS & DEFINITIONS

Symbol	Definition
I_B	Base current: The value of the dc current into the base terminal.
I_C	Collector current: The value of the dc current into the collector terminal.
I_E	Emitter current: The value of the dc current into the emitter terminal.
T_C	Case temperature: The temperature measured at a specified location on the case of a device.
V_{CB}	Collector-base voltage: The dc voltage between the collector and the base.
V_{CBO}	Collector-base voltage, base open: The voltage between the collector and base terminals when the emitter terminal is open-circuited.
V_{CC}	Collector-supply voltage: The supply voltage applied to a circuit connected to the collector.
V_{CEO}	Collector-emitter voltage, base open: The voltage between the collector and the emitter terminals when the base terminal is open-circuited.
V_{CE}	Collector-emitter voltage: The dc voltage between the collector and the emitter.
V_{EB}	Emitter-base voltage: The dc voltage between the emitter and the base.
V_{EBO}	Emitter-base voltage, collector open: The voltage between the emitter and base terminals with the collector terminal open-circuited.

ELECTRICAL CHARACTERISTICS @ T_A = +25 °C unless otherwise noted

Characteristics		Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage I_C = 200 mA	2N6383 2N6384 2N6385	$V_{(BR)CEO}$	40 60 80		V
Collector-Emitter Breakdown Voltage I_C = 200 mA, R_{BB} = 100 Ω	2N6383 2N6384 2N6385	$V_{(BR)CER}$	40 60 80		V
Collector-Emitter Cutoff Current V_{CE} = 40 V V_{CE} = 60 V V_{CE} = 80 V	2N6383 2N6384 2N6385	I_{CEO}		1.0	mA
Collector-Emitter Cutoff Current V_{CE} = 40 V, V_{BE} = 1.5 V V_{CE} = 60 V, V_{BE} = 1.5 V V_{CE} = 80 V, V_{BE} = 1.5 V	2N6383 2N6384 2N6385	I_{CEX}		100	µA
Emitter-Base Cutoff Current V_{EB} = 5.0 V		I_{EBO}		5.0	mA
Collector-Emitter Cutoff Current V_{CE} = 40 V V_{CE} = 60 V V_{CE} = 80 V	2N6383 2N6384 2N6385	I_{CBO}		1.0	mA
ON CHARACTERISTICS					
Forward-Current Transfer Ratio I_C = 5.0 A, V_{CE} = 3.0 V I_C = 10 A, V_{CE} = 3.0 V I_C = 5.0 A, V_{CE} = 3.0 V, T_A = -55 ºC		h_{FE}	1,000 100 200	20,000	
Collector-Emitter Saturation Voltage I_C = 5.0 A, I_B = 10 mA I_C = 10 A, I_B = 0.1 A		$V_{CE(sat)}$		2.0 3.0	V
Base-Emitter Voltage Non-saturated V_{CE} = 3.0 V, I_C = 5.0 A V_{CE} = 3.0 V, I_C = 10 A		$V_{BE(on)}$		2.8 4.5	V
DYNAMIC CHARACTERISTICS					
Magnitude of Common Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio I_C = 1.0 A, V_{CE} = 5.0 V, f = 1.0 MHz		|hfe|	20	300	
Output Capacitance V_{CB} = 10 V, I_E = 0, f = 100 kHz ≤ f ≤ 1 MHz		Cobo		200	pF

ELECTRICAL CHARACTERISTICS @ T_C = 25 °C unless otherwise noted. (continued)

SWITCHING CHARACTERISTICS

Turn-On Time V_{CC} = 30 V, I_C = 5.0 A; I_B= 20 mA	t_{on}		2.5	µs
Turn-Off Time V_{CC} = 30 V, I_C = 5.0 A; I_{B1}= -I_{B2} = 20 mA	t_{off}		10	µs

SAFE OPERATING AREA (See Figures 1 and 2 and MIL-STD-750,Test Method 3053)

DC Tests

T_C = +25 °C, t = 1 second, 1 Cycle

Test 1

V_{CE} = 10 V, I_C = 10 A

Test 2

V_{CE} = 30 V, I_C = 3.33 A

Test 3

V_{CE} = 40 V, I_C = 1.5 A (2N6383)

V_{CE} = 60 V, I_C = 0.4 A (2N6384)

V_{CE} = 80 V, I_C = 0.16 A (2N6385)

SAFE OPERATING AREA

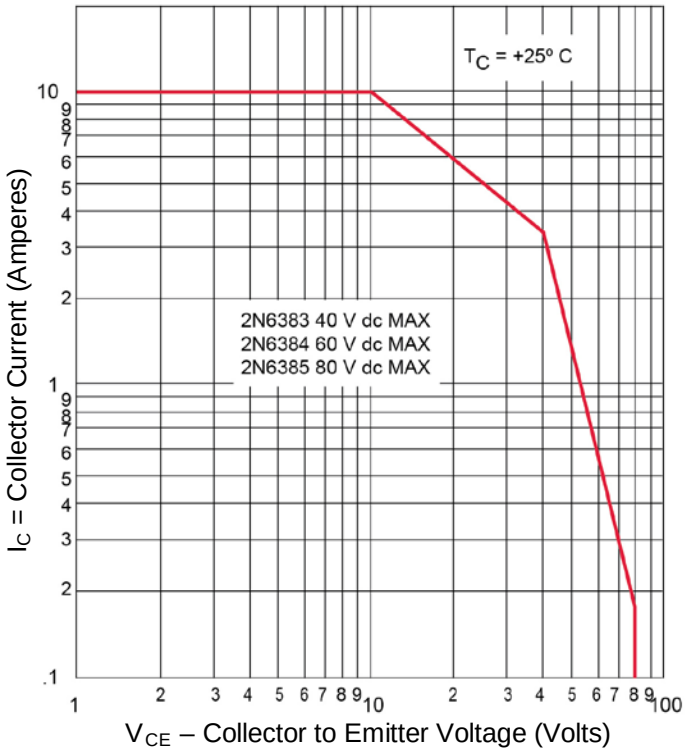


FIGURE 1
Maximum Safe Operating Graph (continuous dc)

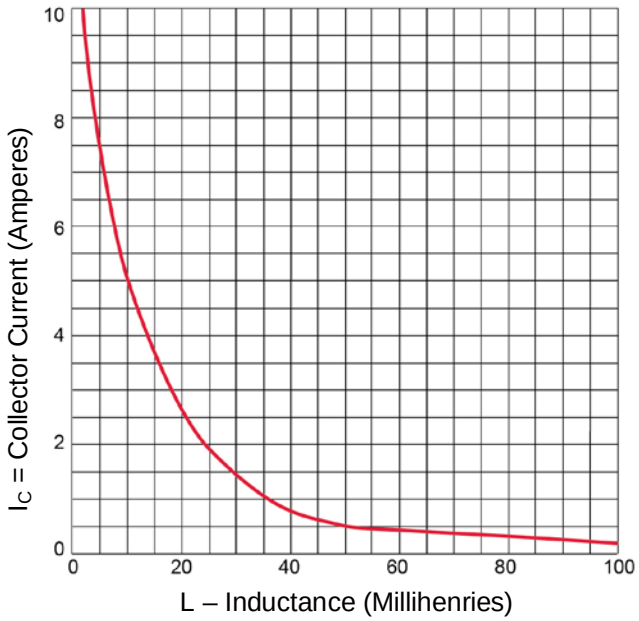
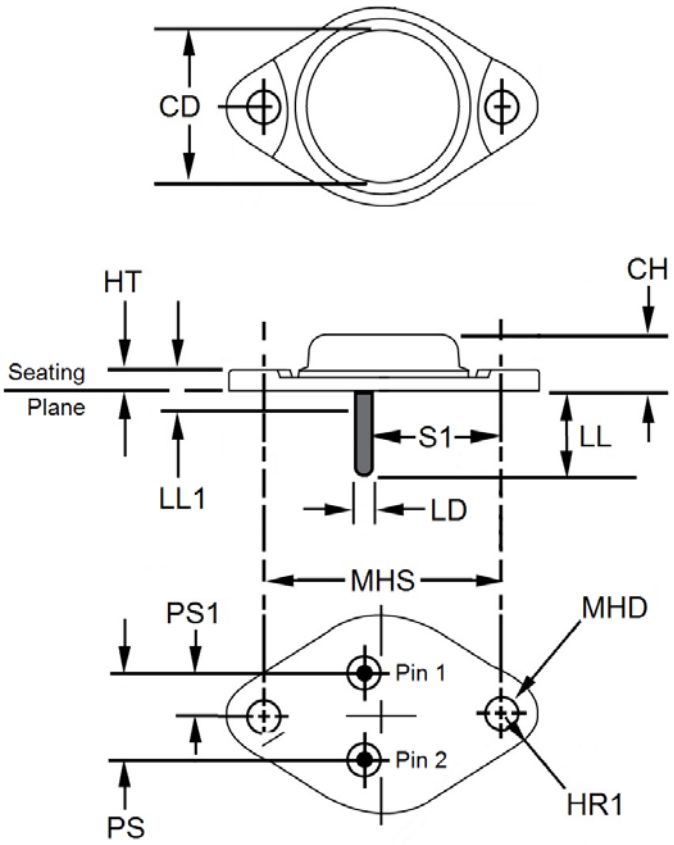


FIGURE 2
Safe Operating Area for Switching Between Saturation and Cutoff (unclamped inductive load)

PACKAGE DIMENSIONS



Ltr	Dimensions				Notes
	Inches		Millimeters		
	Min	Max	Min	Max	
CD	-	0.875	-	22.23	3
CH	0.250	0.450	6.35	11.43	
HR	0.495	0.525	12.57	13.34	
HR1	0.131	0.188	3.33	4.78	4
HT	0.060	0.135	1.52	3.43	
LD	0.038	0.043	0.97	1.09	5, 6
LL	0.312	0.500	7.92	12.70	5
LL1	-	0.050	-	1.27	5, 6
MHD	0.151	0.161	3.84	4.09	7
MHS	1.177	1.197	29.90	30.40	
PS	0.420	0.440	10.67	11.18	8, 9
PS1	0.205	0.225	5.21	5.72	5, 8, 9
S1	0.655	0.675	16.64	17.15	8

NOTES:

1. Dimensions are in inches. Millimeters are given for information only.
2. Terminal 1 is the base and terminal 2 is the emitter. The collector shall be electrically connected to the case.
3. Body contour is optional within zone defined by dimension CD.
4. Applies to both ends.
5. Applies to both terminals.
6. Dimension LD applies between L1 and LL. Lead diameter shall not exceed twice dimension LD within dimension L1. Diameter is uncontrolled in dimension L1.
7. Two holes.
8. These dimensions shall be measured at points 0.050 inch (1.27 mm) to 0.055 inch (1.40 mm) below the seating plane. When gauge is not used, measurement shall be made at seating plane.
9. The seating plane of the header shall be flat within 0.001 inch (0.03 mm) concave to 0.004 inch (0.10 mm) convex inside a 0.930 inch (23.62 mm) diameter circle on the center of the header and flat within 0.001 inch (0.03 mm) concave to 0.006 inch (0.15 mm) convex overall.
10. Mounting holes shall be deburred on the seating plane side.
11. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

See schematic on next page

SCHEMATIC